

# TinyLogic UHS Buffer with Three-State Output NC7SZ126

# **Description**

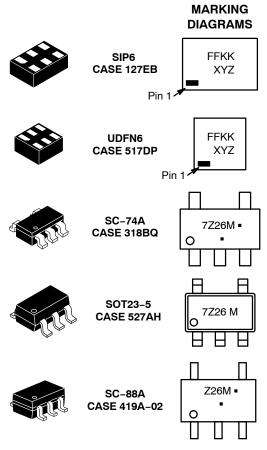
The NC7SZ126 is a single buffer with three–State output from **onsemi**'s Ultra–High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad  $V_{\rm CC}$  operating range. The device is specified to operate over the 1.65 V to 5.5 V  $V_{\rm CC}$  operating range. The inputs and output are high impedance above ground when  $V_{\rm CC}$  is 0 V. Inputs tolerate voltages up to 5.5 V independent of  $V_{\rm CC}$  operating voltage. The output tolerates voltages above  $V_{\rm CC}$  in the 3–STATE condition.

#### **Features**

- Ultra-High Speed:  $t_{PD}$  = 2.6 ns (Typical) into 50 pF at 5 V  $V_{CC}$
- High Output Drive: ±24 mA at 3 V V<sub>CC</sub>
- Broad V<sub>CC</sub> Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX when Operated at 3.3 V V<sub>CC</sub>
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPak<sup>TM</sup> Packages
- Space–Saving SOT23–5, SC–74A and SC–88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



FF, 7Z26, Z26 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code

XY = 2-Digit Date Code Format
Z = Assembly Plant Code

M = Date Code ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

# **Pin Configurations**

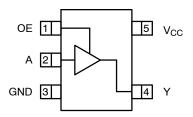


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

# OE 1 6 V<sub>CC</sub> 5 NC A 2 GND 3 4 Y

Figure 3. MicroPak (Top Through View)

# **PIN DEFINITIONS**

Pin # SOT23-5 / SC-88A / SC74A	Pin # MicroPak	Name	Description
1	1	OE	Input
2	2	Α	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V <sub>CC</sub>	Supply Voltage
	5	NC	No Connect

# **FUNCTION TABLE**

Inp	Output	
OE	Α	Υ
Н	L	L
Н	Н	Н
L	Х	Z

H = HIGH Logic Level L = LOW Logic Level X = HIGH or LOW Logic Level Z = HIGH Impedance State

## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5	6.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current V <sub>IN</sub> < 0 V		-	-50	mA
l <sub>ok</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-50	mA
l <sub>out</sub>	DC Output Current		-	±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current		-	±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		-	+150	°C
TL	Junction Lead Temperature (Solder	ring, 10 Seconds)	-	+260	°C
$P_{D}$	Power Dissipation in Still Air	n in Still Air SC-74A / SOT23-5		390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	2000	V
	Charge Device Model, JEDEC: JES	SD22-C101	-	1000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage Operating		1.65	5.5	٧
	Supply Voltage Data Retention		1.5	5.5	
V <sub>IN</sub>	Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage	Active State	0	V <sub>CC</sub>	V
		Three-State	0	5.5	
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Times	V <sub>CC</sub> = 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V <sub>CC</sub> = 3.3 V ±0.3 V	0	10	
		V <sub>CC</sub> = 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

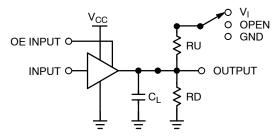
# DC ELECTRICAL CHARACTERISTICS

				T	\ = +25°	°C	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage	1.65 to 1.95		0.65 V <sub>CC</sub>	-	-	0.65 V <sub>CC</sub>	-	V
		2.30 to 5.50		0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
V <sub>IL</sub>	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
		2.30 to 5.50		-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	1
V <sub>OH</sub>	HIGH Level Output Voltage	1.65	$V_{IN} = V_{IH}$ or $V_{IL}$ ,	1.55	1.65	-	1.55	-	V
		1.80	I <sub>OH</sub> = -100 μA	1.70	1.80	-	1.70	-	
		2.30		2.20	2.30	-	2.20	-	1
		3.00		2.90	3.00	-	2.90	-	1
		4.50		4.40	4.50	-	4.40	-	1
		1.65	I <sub>OH</sub> = -4 mA	1.29	1.52	-	1.29	-	1
		2.30	I <sub>OH</sub> = -8 mA	1.90	2.15	-	1.90	-	1
		3.00	I <sub>OH</sub> = -16 mA	2.40	2.80	-	2.40	-	1
		3.00	I <sub>OH</sub> = -24 mA	2.30	2.68	-	2.30	-	1
		4.50	I <sub>OH</sub> = -32 mA	3.80	4.20	-	3.80	-	1
V <sub>OL</sub>	LOW Level Output Voltage	1.65	$V_{IN} = V_{IH}$ or $V_{IL}$ ,	-	0.00	0.10	-	0.10	V
		1.80	I <sub>OL</sub> = 100 μA	_	0.00	0.10	-	0.10	1
		2.30		-	0.00	0.10	-	0.10	1
		3.00		_	0.00	0.10	_	0.10	1
		4.50		_	0.00	0.10	_	0.10	1
		1.65	I <sub>OL</sub> = 4 mA	_	0.80	0.24	_	0.24	1
		2.30	I <sub>OL</sub> = 8 mA	-	0.10	0.30	-	0.30	1
		3.00	I <sub>OL</sub> = 16 mA	_	0.15	0.40	_	0.40	1
		3.00	I <sub>OL</sub> = 24 mA	-	0.22	0.55	-	0.55	1
		4.50	I <sub>OL</sub> = 32 mA	-	0.22	0.55	-	0.55	1
I <sub>IN</sub>	Input Leakage Current	1.65 to 5.5	V <sub>IN</sub> = 5.5 V, GND	-	_	±1	-	±10	μА
I <sub>OZ</sub>	3-STATE Output Leakage	1.65 to 5.5	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_O = V_{CC}$ or GND	-	-	±1	-	±10	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	0	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	_	-	1	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	1.65 to 5.50	V <sub>IN</sub> = 5.5 V, GND	-	_	2	-	20	μΑ

# **AC ELECTRICAL CHARACTERISTICS**

				-	Γ <sub>A</sub> = +25°0	;	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay (Figure 4, 6)	1.65	C <sub>L</sub> = 15 pF,	-	6.4	13.2	-	13.8	ns
		$1.80$ $R_D = 1 M\Omega$ $S_1 = OPEN$	-	5.3	11.0	-	11.5		
			-	3.4	7.5	-	8.0		
		3.30 ±0.30	]	-	2.5	5.2	-	5.5	
		5.00 ±0.50	]	-	2.1	4.5	-	4.8	
		3.30 ±0.30		-	3.2	5.7	-	6.0	
		5.00 ±0.50	$R_D = 500 \Omega$ $S_1 = OPEN$	-	2.6	5.0	-	5.3	
$t_{PZL}, t_{PZH}$	Output Enable Time	1.65		-	8.4	15.0	-	15.6	ns
	(Figure 4, 6)	1.80 $R_D = 500 \Omega$ $RU = 500 \Omega$ $S_1 = GND \text{ for } t_{PZH}$ $S_2 = V_{IN} \text{ for } t_{PZH}$	1	6.1	11.5	-	12.0		
			$S_1 = GND \text{ for } t_{PZH}$ $S_1 = V_{IN} \text{ for } t_{PZL}$	1	3.8	8.0	-	8.5	
		3.30 ±0.30		-	3.2	5.7	-	6.0	
		5.00 ±0.50	]	_	2.3	5.0	-	5.3	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time	1.65	C <sub>L</sub> = 50 pF,	_	6.5	13.2	-	14.5	
	(Figure 4, 6)	1.80	$R_D$ = 500 $Ω$ RU = 500 $Ω$	-	5.6	11.0	-	12	
		2.50 ±0.20	$S_1 = GND \text{ for } t_{PHZ}$ $S_1 = V_{IN} \text{ for } t_{PLZ}$	-	4.0	8.0	-	8.5	
		3.30 ±0.30	$V_{IN} = 2 \cdot V_{CC}$	ı	3.5	5.7	_	6.0	
		5.00 ±0.50		ı	2.5	4.7	-	5.0	
C <sub>IN</sub>	Input Capacitance	0.00		ı	4	_	-	_	pF
C <sub>OUT</sub>	Output Capacitance	0.00		ı	8	_	-	_	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 2) (Figure 5)	3.30		ı	17	_	-	_	pF
	(Note 2) (Figure 3)	5.00		1	24	-	-	-	

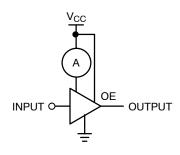
<sup>2.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression: I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).



## NOTE:

3.  $C_L$  includes load and stray capacitance; Input PRR = 1.0 MHz;  $t_W$  = 500 ns

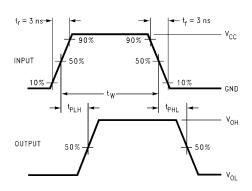
# Figure 4. AC Test Circuit



#### NOTE:

4. Input = AC Waveform;  $t_r = t_f = 1.8$  ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 5. I<sub>CCD</sub> Test Circuit



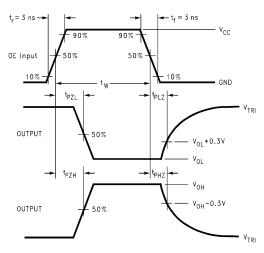


Figure 6. AC Waveforms

# **ORDERING INFORMATION**

Part Number	Top Mark	Packages	Shipping <sup>†</sup>
NC7SZ126M5X	7Z26	SC-74A	3000 / Tape & Reel
NC7SZ126M5X-L22090	7Z26	SOT23-5	3000 / Tape & Reel
NC7SZ126P5X	Z26	SC-88A	3000 / Tape & Reel
NC7SZ126P5X-F22057	Z26	SC-88A	3000 / Tape & Reel
NC7SZ126L6X	FF	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ126L6X-L22175	FF	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ126FHX	FF	UDFN6, MicroPak2	5000 / Tape & Reel
NC7SZ126FHX-L22175	FF	UDFN6, MicroPak2	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak and MicroPak2 are trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.



**DATE 31 AUG 2016** 



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
  4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

  - OTHER LINE IN THE MARK CODE LAYOUT.

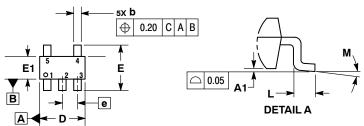
DOCUMENT NUMBER:	98AON13590G	Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SIP6 1.45X1.0		PAGE 1 OF 1

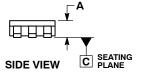
ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



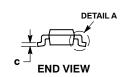


**DATE 18 JAN 2018** 

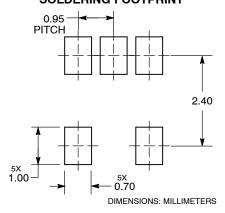




**TOP VIEW** 



# **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- IES:
  DIMENSIONING AND TOLERANCING PER ASME
  Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE
  MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

	MILLIN	IETERS	
DIM	MIN	MAX	
Α	0.90	1.10	
A1	0.01	0.10	
b	0.25	0.50	
С	0.10	0.26	
D	2.85	3.15	
E	2.50	3.00	
E1	1.35	1.65	
е	0.95 BSC		
L	0.20	0.60	
M	0 °	10°	

# **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Document Report Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-74A		PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





# SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

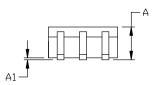
**DATE 11 APR 2023** 

#### NOTES:

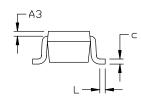
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE, NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,
  OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

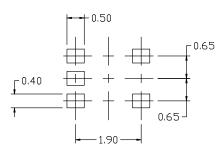
DIM	MI	MILLIMETERS			
INITU	MIN.	N□M.	MAX.		
А	0.80	0.95	1.10		
A1			0.10		
A3	0,20 REF				
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2,20		
Е	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
е	0.65 BSC				
L	0.10	0.15	0.30		

# 5 4 E1 E1 E1 E1 E1 E1



◆ 0.2 M B M





# RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

# GENERIC MARKING DIAGRAM\*



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
<ol><li>EMITTER</li></ol>
3. BASE
<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR</li></ol>

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

# **DOCUMENT NUMBER:**

98ASB42984B

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

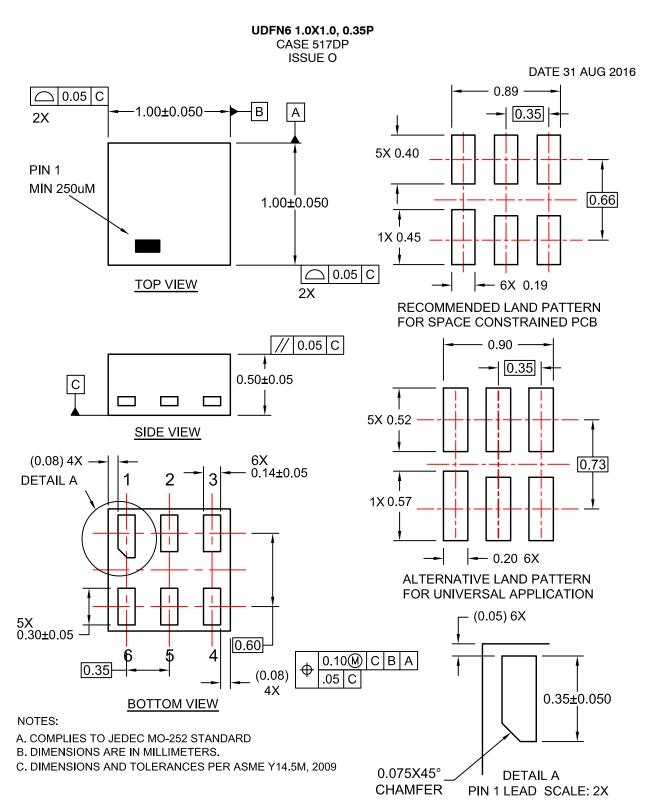
**DESCRIPTION:** 

5. COLLECTOR 2/BASE 1

SC-88A (SC-70-5/SOT-353)

PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



DOCUMENT NUMBER:	98AON13593G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	UDFN6 1.0X1.0, 0.35P		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



REFERENCE



A

F1 F

В

**DATE 09 JUN 2021** 

#### NUTES

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894

DIM

- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.

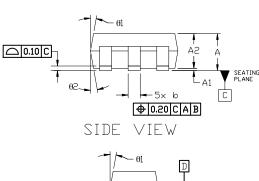
MIN.

DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE O. 08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.

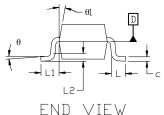
MILLIMETERS

ИПМ.

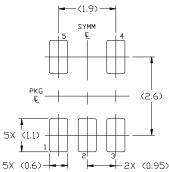
MAX.



TOP VIEW



#### Α 0.90 1.45 A1 0.00 0.15 Α2 0.90 1.15 1.30 b 0.30 0.50 0.08 0.22 n 2.90 BSC 2.80 BSC E1 1.60 BSC 0.95 BSC е 0.45 0.30 0.60 L1 0.60 REF 0.25 REF L2 4° θ 0° 10° 15° θ1 0° 10° θ2 15°



# **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the  $\square N$  Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON34320E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-23, 5 LEAD		PAGE 1 OF 1

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales